

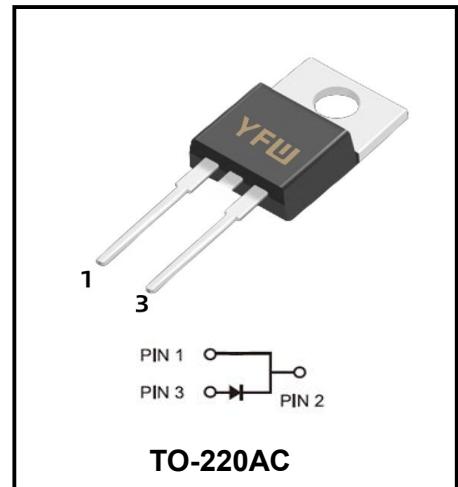
SiC Schottky Barrier Rectifier

Reverse Voltage - 650 V

Forward Current - 6 A

Features

- ◆ Reverse withstand voltage 650V
- ◆ Zero reverse recovery current
- ◆ High working frequency
- ◆ Switch characteristics are not affected by temperature
- ◆ Fast switching speed
- ◆ Positive temperature coefficient of positive pressure drop



Advantages

- ◆ Very low switching loss
- ◆ Higher efficiency
- ◆ Low dependence of the system on the heat sink
- ◆ No thermal collapse in parallel devices

Application

- ◆ Switching mode power supply, AC/DC converter
- ◆ Power factor correction
- ◆ Motor drive
- ◆ PV inverter and wind turbine

Absolute Maximum Rating (Ta=25°C)

Parameter	Symbol	Test conditions	Value	Unit
Peak repetitive reverse voltage	V _{RRM}		650	V
Working Peak Reverse voltage	V _{RWM}		650	V
DC Blocking Voltage	V _{DC}		650	V
Average rectified output current	I _{F(AV)}	T _a =25°C T _a =125°C T _a =150°C	21 11 6	A
Forward repetitive peak current	I _{FRM}	T _C =25°C, tp=10ms, Half Sine Wave T _C =110°C, tp=10ms, Half Sine Wave	35 18	A
Forward surge current	I _{FSM}	T _C =25°C, tp=10ms, Half Sine Wave T _C =110°C, tp=10ms, Half Sine Wave	50 42	A
Power dissipation	P _{tot}	T _a =25°C T _a =110°C	70 26	W
Junction temperature	T _j		-55 ~ +175	°C
Storage temperature	T _{stg}		-55 ~ +175	°C

Thermal characteristics

Parameter	Symbol	Vaule	Unit
Thermal Resistance - Junction to Case	$R_{\theta JC}$	2.3	°C/ W

Electrical Characteristics (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Forward voltage	V_F	$I_F = 6 A, T_j=25^\circ C$ $I_F = 6 A, T_j=175^\circ C$		1.42 1.59	1.6 1.8	V
Reverse current	I_R	$V_R = 650V, T_j=25^\circ C$ $V_R = 650V, T_j=175^\circ C$		2 15	30 120	μA
Total capacitive charge	Q_C	$V_R = 400V, I_F = 6 A$ $di/dt=500A/\mu s, T_j=25^\circ C$		23		nC
Total capacitance	C	$V_R = 0V, T_j=25^\circ C, f=1MHz$ $V_R = 200V, T_j=25^\circ C, f=1MHz$ $V_R = 400V, T_j=25^\circ C, f=1MHz$		423 44 37		pF

Typical Characteristics

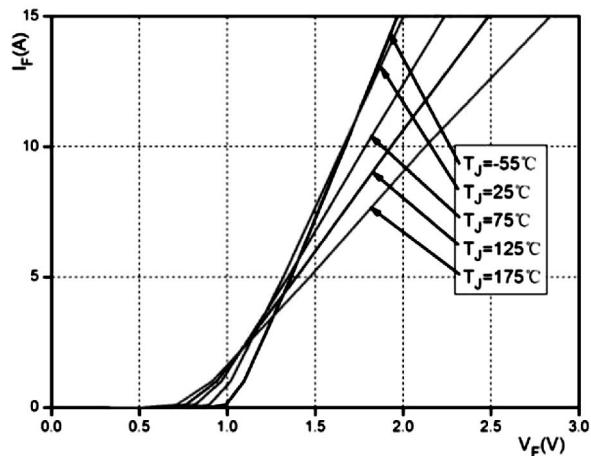


Figure 1. Forward Characteristics

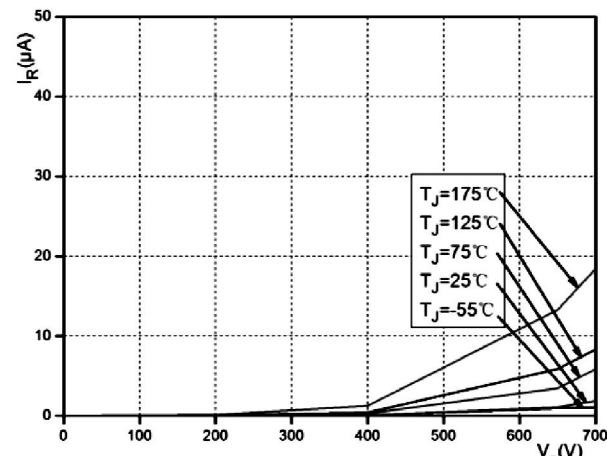


Figure 2. Reverse Characteristics

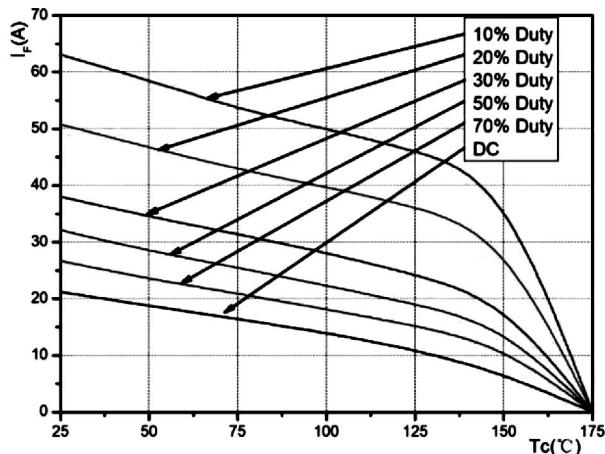


Figure 3. Load current

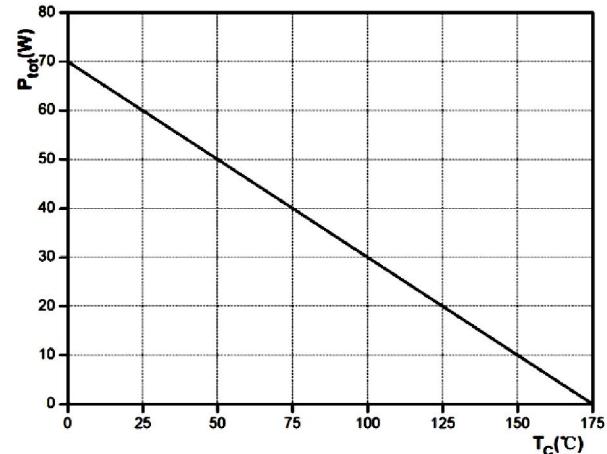


Figure 4. Dissipated power curve

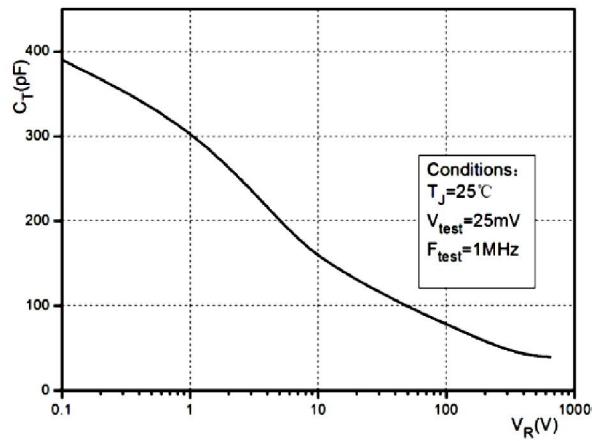


Figure 5. Capacitance vs reverse voltage

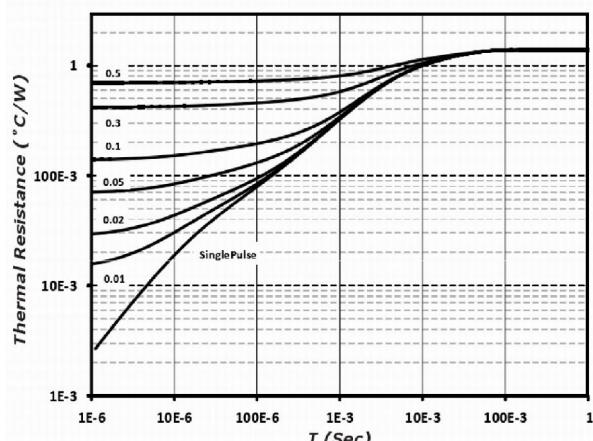
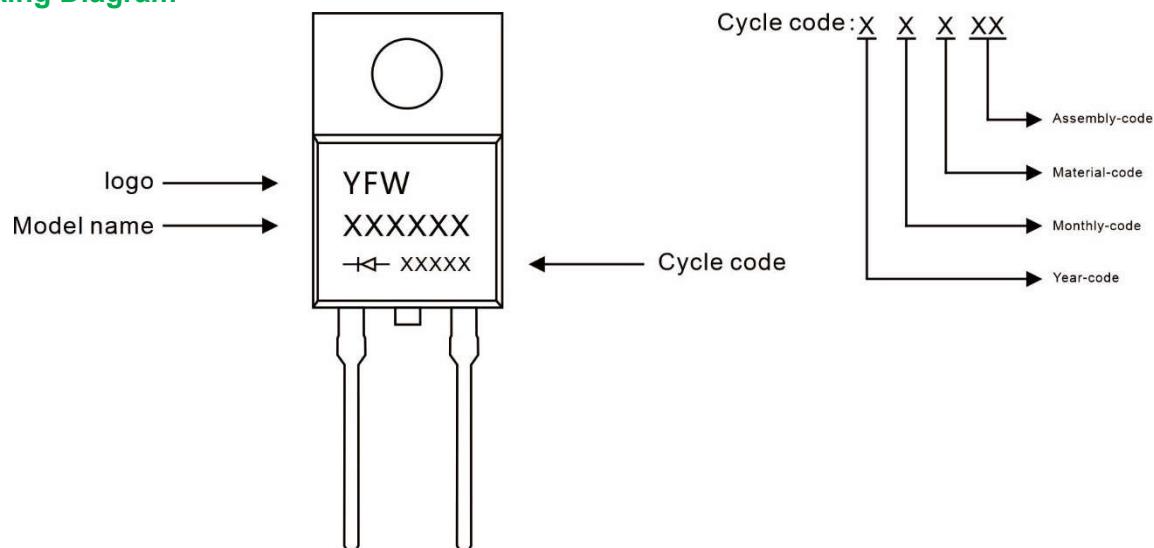


Figure 6. Thermal Impedance Junction-to-Case

Marking Diagram



Ordering information

Model name	Package	Unit Weight	Base Quantity	Packing Quantity
YFWD306065AC	TO-220AC	0.067oz(1.9g)	50pcs/tube	1000PCS/Box 5000PCS/Carton

Package Dimensions

TO-220AC

Symbol	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	10.15	10.35	0.400	0.407
B	2.65	2.95	0.104	0.116
C	3.70	3.90	0.146	0.154
D	28.5	29.5	1.12	1.16
E	1.3	1.45	0.051	0.057
F	0.8	1.1	0.031	0.043
G	2.9	3.3	0.114	0.130
H	15.0	16.0	0.591	0.630
I	0.38	0.42	0.015	0.017
J	4.45	4.55	0.175	0.179
K	1.25	1.35	0.049	0.053
L	6.35	6.55	0.250	0.258
M	Typ5.08		Typ0.2	
N	Typ2.54		Typ0.1	
O	0.76	0.84	0.030	0.033
P	3.1	3.3	0.122	0.130

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